No. of Printed Pages: 02

SEAT No. SARDAR PATEL UNIVERSITY

B.Sc. (4th Semester) Examination Tuesday,9th April 2019 10:00 am to 01:00 pm

Electronics

US04CELE01- Electronics Devices and Applications

| | | | · To | otal Marks : 70 | |
|--|----------------------|----------------------------|--------------------------|-----------------|--|
| Q.1 | Multiple choice | questions. | | [10] | |
| | · | controlled Device. | | | |
| | | (b) Current | (c) Power | | |
| 2. | | | t normally remains cons | tant over the | |
| | range of fo | | | | |
| | | (b) Middle | (c) High | | |
| 3. | | e best FET biasing circuit | | | |
| | | | (c) Fixed Voltage B | ias | |
| 4. | ` ' | | output signal are | | |
| | each other | | | | |
| | (a) 180 out of | (b) 90 out of | (c) 270 out of | | |
| 5. | | | OSFET the line represent | ing the channel | |
| | | | ot exist until the | | |
| | applied. | | | | |
| | (a) Gaté | (b) Drain | (c) Source | | |
| 6 | | | wn as follower. | | |
| | | o) Gate (c) Source | | | |
| 7. The input impedance of Field Effect Transistor is | | | | | |
| | · · | (b) Low (| | | |
| 8 | | | eated to produce | emission. | |
| | | (b) Secondary | | | |
| 9 | | ı emit infrared | | | |
| | | (b) GaAsP | | ÷ | |
| 1 | .0. The liquid cryst | al display is made from | compounds. | | |
| | | | (c) Semiconductor | | |
| | | | | [20] | |
| | | questions in brief | E | [20] | |
| | • | nplifier Gain falls at low | Frequencyr | | |
| | Define Decibel. | | | | |
| | List different FE | · | | | |
| 4. | . Draw the Symbo | ls of depletion enhance | ment mode MUSFEI. | | |
| | | <u></u> | | (የፓል) | |

| 6. D | Praw the symbols of enhancement mode N-Channel MOSFET. | |
|------|---|-------|
| 7. D | raw the common drain ac equivalent circuit . | |
| 8. D | raw the common source ac equivalent circuit . | |
| 9. D | raw the ac equivalent circuit of common gate amplifier. | |
| 10.\ | What does photoconductive cell consists of ? | |
| 11.\ | What is Dynamic scattering ? | |
| 12.\ | What is an LED ? | |
| | | |
| Q.3 | Explain in detail the frequency response of an amplifier giving necessary fig | ures. |
| | | [10] |
| | OR | |
| | [a] Explain the drain characteristics of N channel JFET with external bias. | [06] |
| | b] Discuss in detail the depletion region of N channel JFET. | [04] |
| | | |
| Q.4 | Discuss in detail the enhancement made MOSEST vivian and state of | |
| Q,4 | Discuss in detail the enhancement mode MOSFET giving necessary figure | |
| | OR | [10] |
| Q.4 | Dicuss in detail the depletion enhancement MOSFET giving necessary fig | uroc |
| ٠, ١ | bloads in detail the depletion enhancement (MOSFET giving necessary ligh | [10] |
| | | [IU] |
| Q.5 | Discuss in detail the working of common source amplifier giving necessar | v |
| | figures . | [10] |
| | OR | 11 |
| Q.5 | Draw the circuit of common drain amplifier and explain its working in det | ail, |
| | | [10] |
| Q.6 | Discuss in detail the photo multiplier tube with the help of necessary | |
| | diagrams. | [10] |
| | OR | |
| Q.6 | Discuss in detail the Liquid Crystal Display giving necessary diagrams. | [10] |
| | | |
| | | |
| | | |

5. Draw the potential divider circuit using P channel FET.